

## 1MBI 300S-120

## IGBT MODULE ( S-Series )

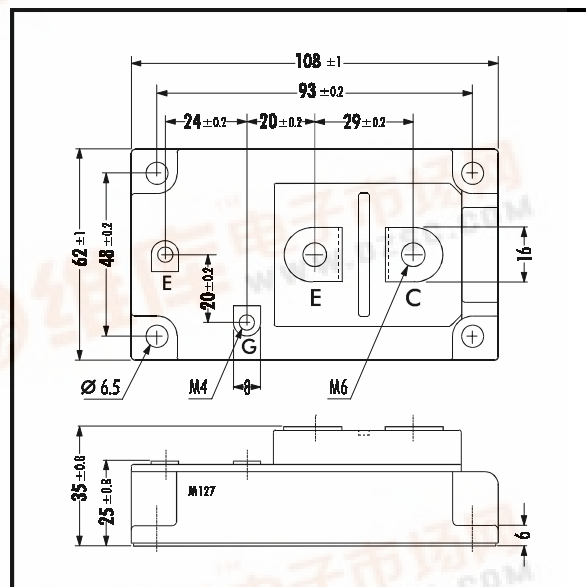
## ■ Features

- NPT-Technology
- Square SC SOA at  $10 \times I_C$
- High Short Circuit Withstand-Capability
- Small Temperature Dependence of the Turn-Off Switching Loss
- Low Losses And Soft Switching

## ■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

## ■ Outline Drawing



## ■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (  $T_c=25^\circ\text{C}$  )

| Items                     | Symbols                 | Ratings     | Units                 |
|---------------------------|-------------------------|-------------|-----------------------|
| Collector-Emitter Voltage | $V_{CES}$               | 1200        | V                     |
| Gate -Emitter Voltage     | $V_{GES}$               | $\pm 20$    | V                     |
| Collector Current         | Continuous              | 25°C / 80°C | $I_C$                 |
|                           | 1ms                     | 25°C / 80°C | $I_{C\text{ PULSE}}$  |
|                           | Continuous              |             | $-I_C$                |
|                           | 1ms                     |             | $-I_{C\text{ PULSE}}$ |
| Max. Power Dissipation    | $P_C$                   | 2100        | W                     |
| Operating Temperature     | $T_j$                   | +150        | °C                    |
| Storage Temperature       | $T_{stg}$               | -40 ~ +125  | °C                    |
| Isolation Voltage         | $V_{is}$                | 2500        | V                     |
| Screw Torque              | A.C. 1min.              |             |                       |
|                           | Mounting <sup>*2</sup>  | 3.5         | Nm                    |
|                           | Terminals <sup>*2</sup> | 4.5         | Nm                    |
|                           | Terminals <sup>*2</sup> | 1.7         | Nm                    |

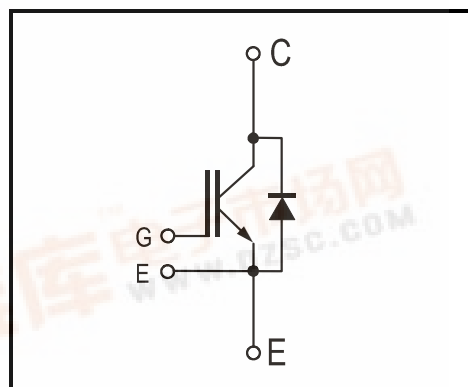
Note: 1\*: All Terminals should be connected together when isolation test will be done.

2\*: Recommendable Value: Mounting 2.5 ~ 3.5 Nm (M5) or (M6) ; Terminal 3.5 ~ 4.5 Nm (M6), 1.3 ~ 1.7 Nm (M4)

• Electrical Characteristics ( at  $T_j=25^\circ\text{C}$  )

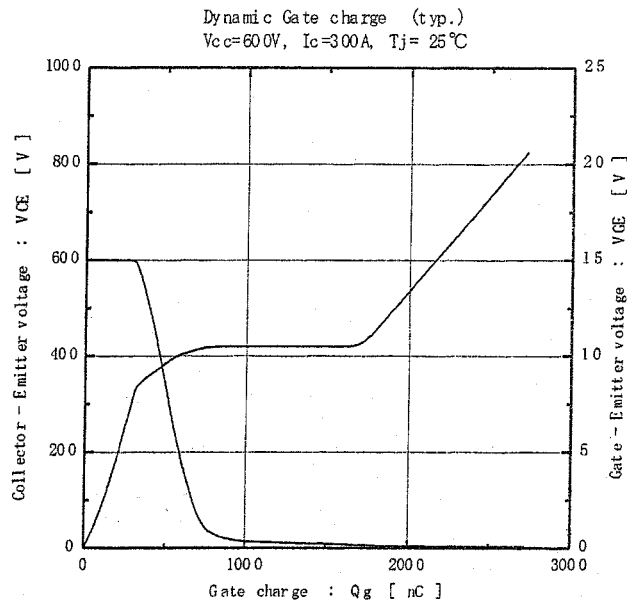
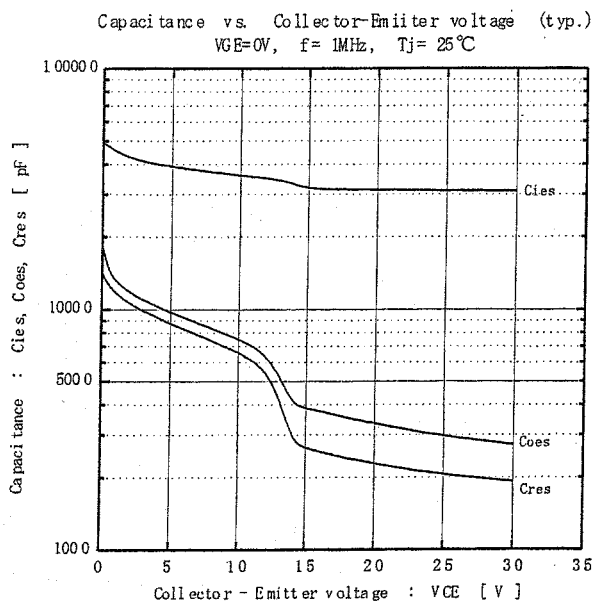
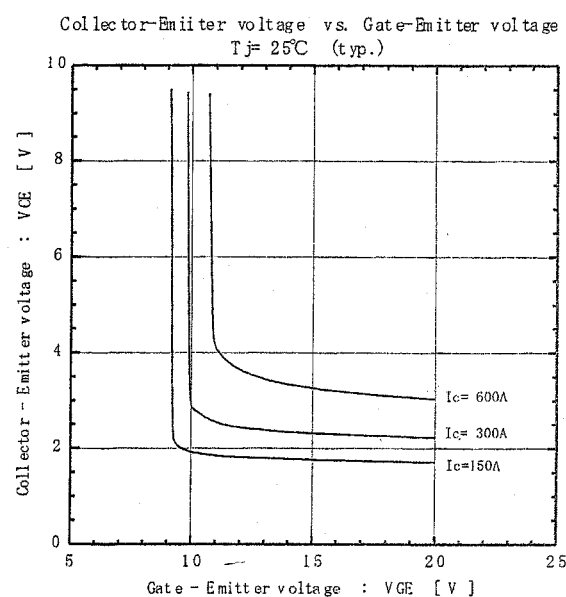
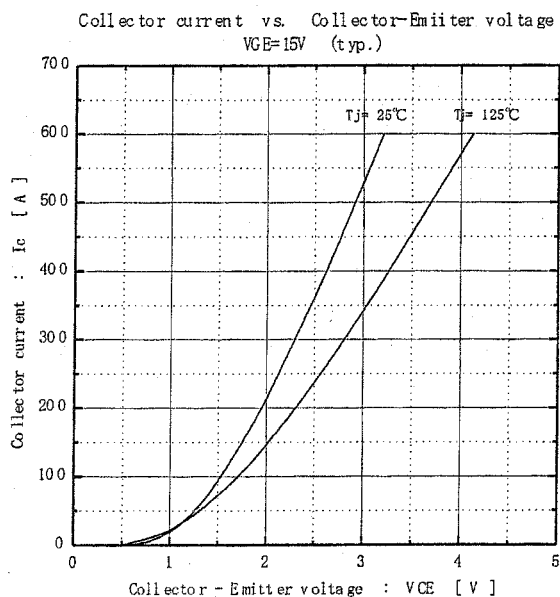
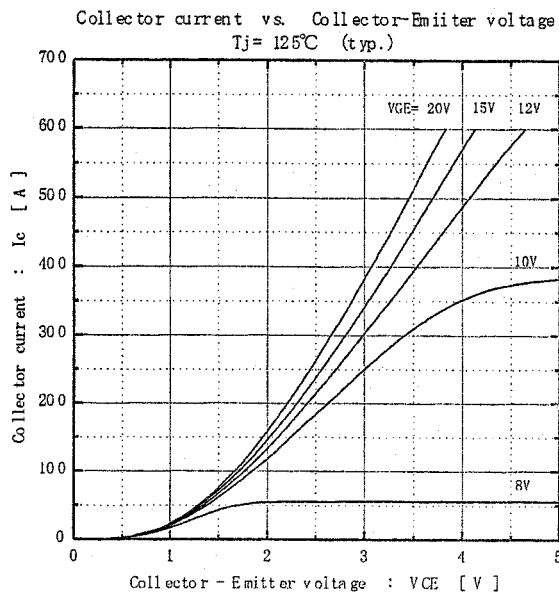
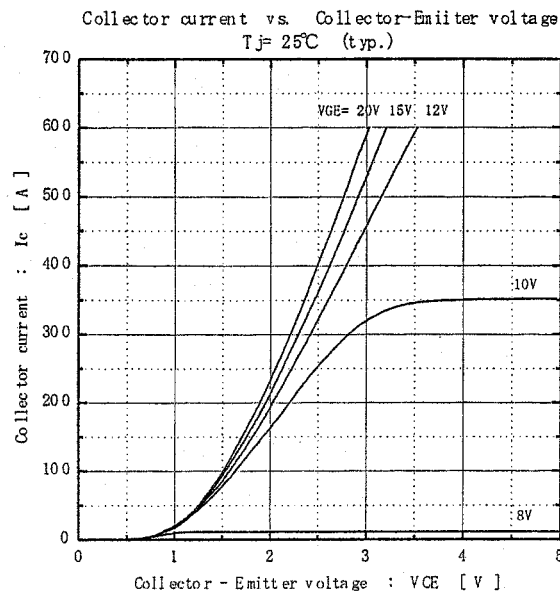
| Items                                | Symbols       | Test Conditions              | Min. | Typ.   | Max. | Units |
|--------------------------------------|---------------|------------------------------|------|--------|------|-------|
| Zero Gate Voltage Collector Current  | $I_{CES}$     | $V_{GE}=0V$ $V_{CE}=1200V$   |      |        | 4.0  | mA    |
| Gate-Emitter Leakage Current         | $I_{GES}$     | $V_{CE}=0V$ $V_{GE}=\pm 20V$ |      |        | 800  | nA    |
| Gate-Emitter Threshold Voltage       | $V_{GE(th)}$  | $V_{GE}=20V$ $I_C=300mA$     | 5.5  | 7.2    | 8.5  | V     |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $V_{GE}=15V$ $I_C=300A$      |      | 2.3    | 2.6  | V     |
| Input Capacitance                    | $C_{ies}$     | $V_{GE}=0V$                  |      | 36'000 |      | pF    |
| Output Capacitance                   | $C_{oes}$     | $V_{CE}=10V$                 |      | 7'500  |      | pF    |
| Reverse Transfer Capacitance         | $C_{res}$     | $f=1MHz$                     |      | 6'600  |      | pF    |
| Turn-on Time                         | $t_{ON}$      | $V_{CC}=600V$                |      | 0.35   | 1.2  | μs    |
|                                      | $t_{r,x}$     | $I_C=300A$                   |      | 0.25   | 0.6  | μs    |
|                                      | $t_{r,i}$     | $V_{GE}=\pm 15V$             |      | 0.10   |      | μs    |
| Turn-off Time                        | $t_{OFF}$     | $R_G=2.7\Omega$              |      | 0.45   | 1.0  | μs    |
|                                      | $t_f$         | Inductive Load               |      | 0.08   | 0.3  | μs    |
| Diode Forward On-Voltage             | $V_F$         | $I_F=300A$ $V_{GE}=0V$       |      | 2.3    | 3.0  | V     |
| Reverse Recovery Time                | $t_{rr}$      | $I_F=300A$                   |      | 2.0    | 350  | ns    |

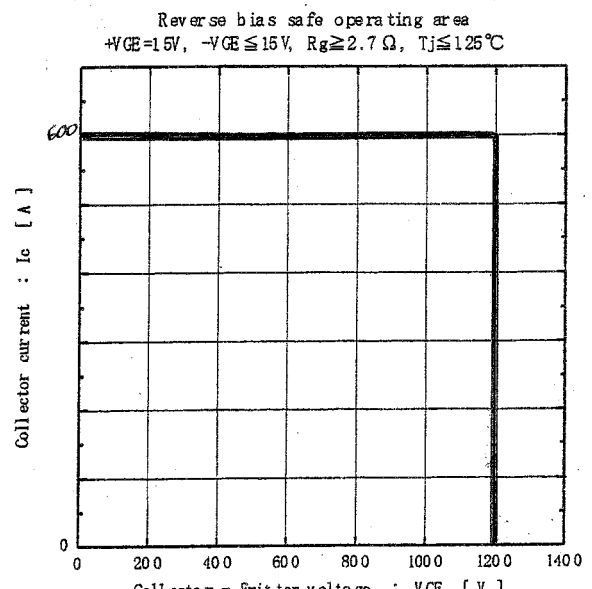
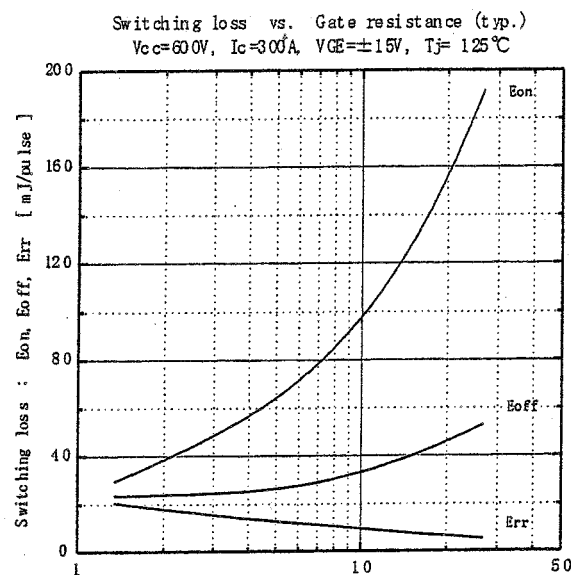
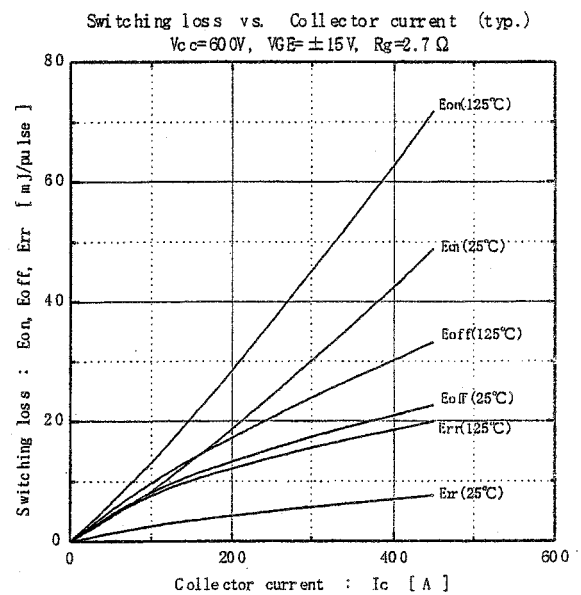
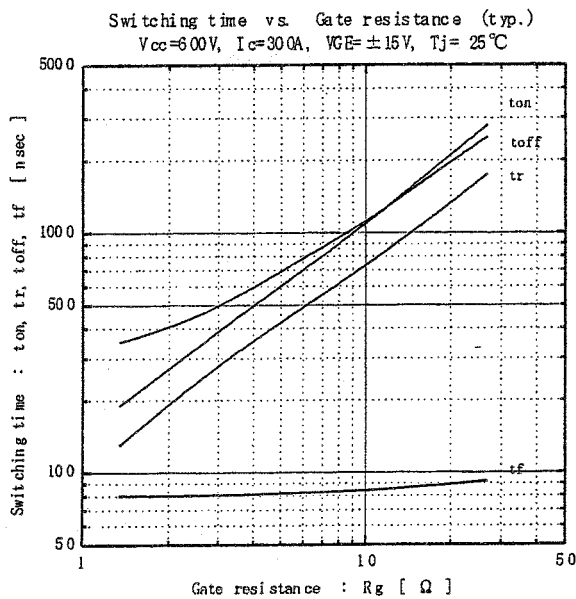
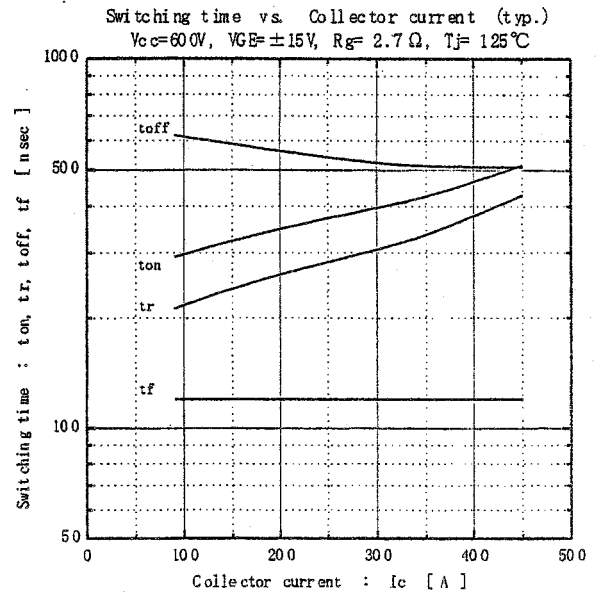
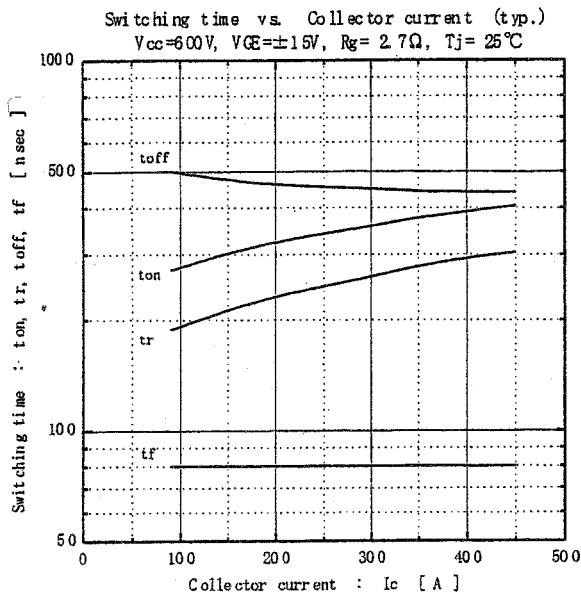
## ■ Equivalent Circuit



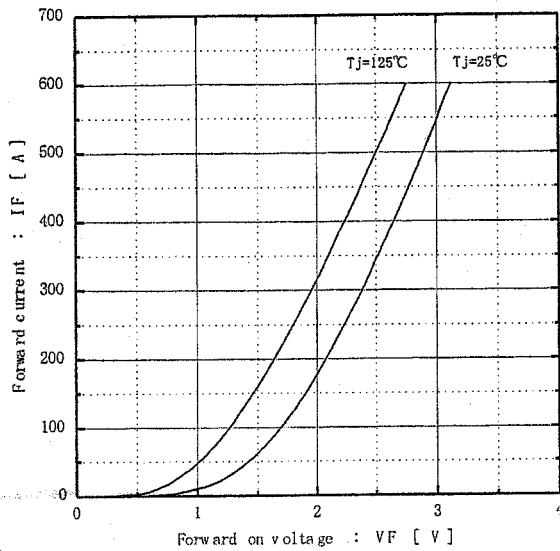
## • Thermal Characteristics

| Items              | Symbols       | Test Conditions | Min. | Typ. | Max. | Units |
|--------------------|---------------|-----------------|------|------|------|-------|
| Thermal Resistance | $R_{th(j-c)}$ | IGBT            |      |      | 0.06 | °C/W  |
|                    | $R_{th(j-c)}$ | Diode           |      |      | 0.17 | °C/W  |

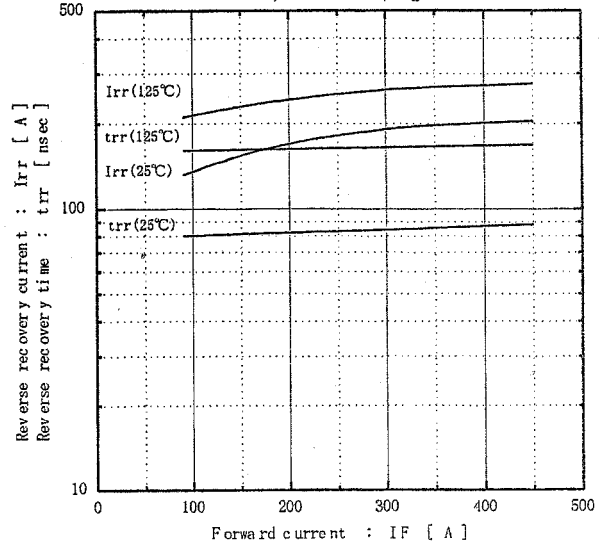




Forward current vs. Forward on voltage (typ.)



Reverse recovery characteristics (typ.)  
 $V_{CC} = 600\text{ V}$ ,  $V_{GE} = \pm 15\text{ V}$ ,  $R_g = 2.7\ \Omega$



Transient thermal resistance

